

STTH120L06TV

Turbo 2 ultrafast high voltage rectifier

Features and benefits

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses

Description

The STTH120L06TV, which is using ST Turbo 2 600 V technology, is specially suited for use in switching power supplies, and industrial applications, as rectification and free-wheeling diode.

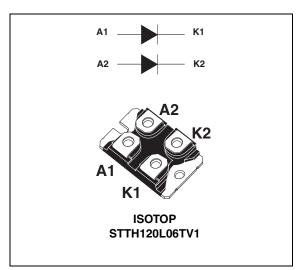


Table 1.Device summary

| Symbol | Value | | | |
|-----------------------|----------|--|--|--|
| I _{F(AV)} | 2 x 60 A | | | |
| V _{RRM} | 600 V | | | |
| Тj | 150 °C | | | |
| V _F (typ) | 0.95 V | | | |
| t _{rr} (max) | 70 ns | | | |

TM: ISOTOP is a trademark of STMicroelectronics

1 Characteristics

Table 2. Absolute ratings (limiting values, per diode)

| Symbol | Parameter | Value | Unit | | |
|---------------------|--|--------------------|-----------|-----|---|
| V _{RRM} | Repetitive peak reverse voltage | 600 | V | | |
| I _{F(RMS)} | RMS forward current | 120 | А | | |
| I _{F(AV)} | Average forward current, $\delta = 0.5$ | $T_c = 65^\circ C$ | Per diode | 60 | А |
| I _{FSM} | Surge non repetitive forward current t _p = 10 ms Sinusoidal | | | 500 | А |
| T _{stg} | Storage temperature range | -55 to + 150 | °C | | |
| Тj | Maximum operating junction temperat | | 150 | °C | |

Table 3.Thermal parameter

| Symbol | Parameter | | Maximum | Unit |
|----------------------|--------------------|-----------|---------|------|
| P | Junction to case | Per diode | 0.98 | |
| R _{th(j-c)} | Sufficient to case | Total | | °C/W |
| R _{th(c)} | Coupling | | 0.1 | |

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j \text{ (diode1)}} = P_{\text{(diode1)}} \times R_{\text{th(j-c) (per diode)}} + P_{\text{(diode2)}} \times R_{\text{th(c)}}$

| | | (1 | | | | | |
|---|-------------------------|-------------------------|-----------------------|------|------|------|------|
| Symbol | Parameter | Test conditions | | Min. | Тур | Max. | Unit |
| IR ⁽¹⁾ Reverse leakage current | T _j = 25 °C | V V | | | 50 | μA | |
| | neverse leakage current | T _j = 125 °C | $V_{R} = V_{RRM}$ | | 50 | 500 | μΑ |
| V _E ⁽²⁾ | Forward voltage drop | T _j = 25 °C | I _F = 60 A | | | 1.55 | V |
| V _F ⁽⁻⁾ | | $T_j = 150 \ ^\circ C$ | | | 0.95 | 1.20 | v |

 Table 4.
 Static electrical characteristics (per diode)

1. Pulse test: t_p = 5 ms, δ < 2 %

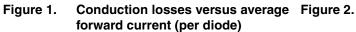
2. Pulse test: $t_p = 380 \ \mu s$, $\delta < 2 \ \%$

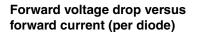
To evaluate the maximum conduction losses use the following equation: P = 0.93 x $I_{F(AV)}$ + 0.0045 I_{F}^{2} (RMS)

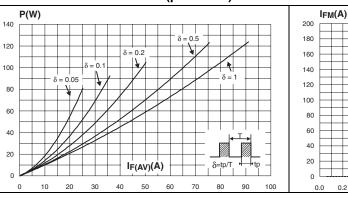


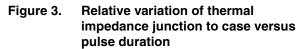
| Symbol | Parameter | Test conditions | | Min. | Тур. | Max. | Unit |
|---------------------------------------|--------------------------|--|--|------|------|------|------|
| t _{rr} Reverse recovery time | T _j = 25 °C | $I_{F} = 0.5 \text{ A},$ $I_{rr} = 0.25 \text{ A},$ $I_{R} = 1 \text{ A}$ | | | 70 | ns | |
| | | I _F = 1 A, dI _F /dt = 50 A/μs, V _R = 30 V | | 75 | 105 | ns | |
| I _{RM} | Reverse recovery current | T _j = 125 °C | I _F = 60 A, dI _F /dt = 400 A/μs, dI _F /dt = 100 A/μs | | 14 | 19 | A |
| t _{fr} | Forward recovery time | T _j = 25 °C | $I_F = 60 \text{ A},$ $dI_F/dt = 200 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}$ | | | 500 | ns |
| V _{FP} | Forward recovery voltage | T _j = 25 °C | $I_F = 60 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}$ | | 3 | | V |

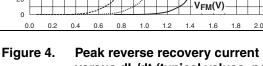
Dynamic characteristics (per diode) Table 5.





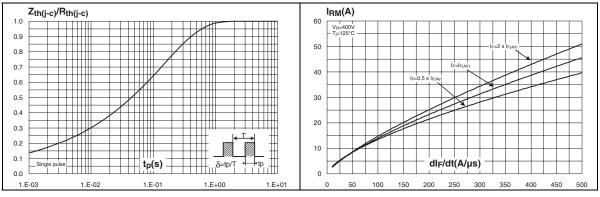






versus dl_F/dt (typical values, per diode)

1.8 2.0 2.2

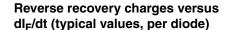


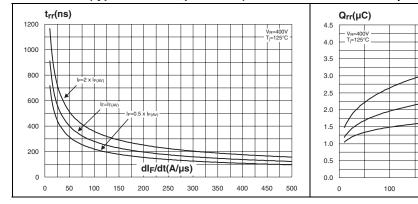
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500

400

Figure 5. Reverse recovery time versus dl_F/dt Figure 6. (typical values, per diode)





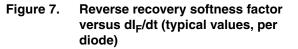


Figure 8. Relative variations of dynamic parameters versus junction temperature

200

IF=2

Ic-

IF=0.5

dl_F/dt(A/µs)

300

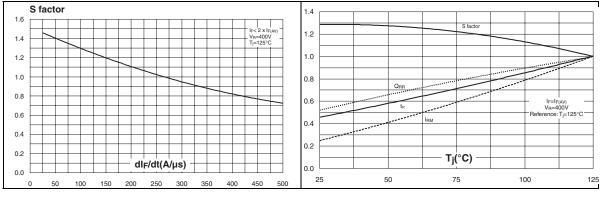
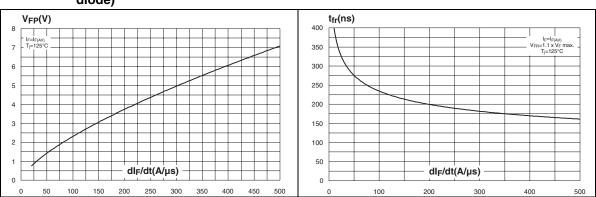


Figure 9. Transient peak forward voltage versus dl_F/dt (typical values, per diode)

Figure 10. Forward recovery time versus dl_F/dt (typical values, per diode)





| | C(pF) |
|------|---|
| 1000 | F=1MHz V _{0SC} =20mV _{RMS} T ₁ =25°C |
| | |
| 100 | |
| 100 | |
| | |
| 10 | |
| | 1 10 100 1000 |

Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)

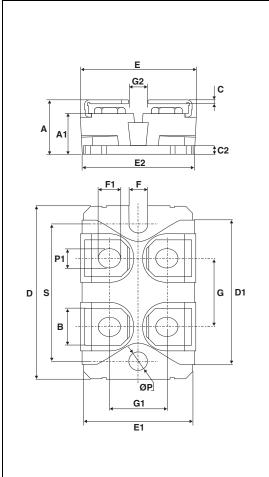


2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 1.3 N·m
- Maximum torque value: 1.5 N·m

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Table 6. ISOTOP dimensions



| | Dimensions | | | | |
|------|------------|--------|------------|-------|--|
| Ref. | Millin | neters | Inches | | |
| | Min. | Max. | Min. | Max. | |
| Α | 11.80 | 12.20 | 0.465 | 0.480 | |
| A1 | 8.90 | 9.10 | 0.350 | 0.358 | |
| В | 7.8 | 8.20 | 0.307 | 0.323 | |
| С | 0.75 | 0.85 | 0.030 | 0.033 | |
| C2 | 1.95 | 2.05 | 0.077 | 0.081 | |
| D | 37.80 | 38.20 | 1.488 | 1.504 | |
| D1 | 31.50 | 31.70 | 1.240 | 1.248 | |
| Е | 25.15 | 25.50 | 0.990 | 1.004 | |
| E1 | 23.85 | 24.15 | 0.939 | 0.951 | |
| E2 | 24.8 | 0 typ. | 0.976 typ. | | |
| G | 14.90 | 15.10 | 0.587 | 0.594 | |
| G1 | 12.60 | 12.80 | 0.496 | 0.504 | |
| G2 | 3.50 | 4.30 | 0.138 | 0.169 | |
| F | 4.10 | 4.30 | 0.161 | 0.169 | |
| F1 | 4.60 | 5.00 | 0.181 | 0.197 | |
| Р | 4.00 | 4.30 | 0.157 | 0.69 | |
| P1 | 4.00 | 4.40 | 0.157 | 0.173 | |
| S | 30.10 | 30.30 | 1.185 | 1.193 | |



3 Ordering information

Table 7. Ordering information

| Order code | Marking | Package | Weight | Base qty | Delivery mode |
|---------------|---------------|---------|--------------------------|---------------------|------------------|
| STTH120L06TV1 | STTH120L06TV1 | ISOTOP | 27 g (without screws) | 10 (with screws) | Tube |

4 Revision history

Table 8.Document revision history

| Date | Revision | Changes | |
|-------------|----------|---|--|
| 07-Sep-2004 | 1 | First issue. | |
| 04-Apr-2011 | 2 | Updated Chapter 2: Package information. | |



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